

# HL6347MG/48MG

Circular Beam Low Operating Current

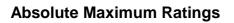
ODE-208-019 (Z) Rev.0 Jul. 01, 2005

## Description

The HL6347MG/48MG are 0.63  $\mu$ m band AlGaInP laser diodes can be operated with low operating current. These products were designed by self aligned refractive index (SRI) active layer structure. These are suitable as a light source for laser levelers, laser scanners and optical equipment for measurement.

### Features

- Optical output power : 10 mW CW
- Single longitudinal mode
- Visible light power : 635 nm Typ
- Low operating current : 35 mA Typ
- Low aspect ratio : 1.2 Typ
- Operating temperature  $:+50^{\circ}C$
- TM mode oscillation



Package Type	Internal Circuit	Internal Circuit		
• HL6347MG/48MG: MG	HL6347MG	• HL6348MG		
		1 3 PD ↓ LD 2		

		$(T_{\rm C} = 25^{\circ}{\rm C})$		
Item	Symbol	Ratings	Unit	
Optical output power	Po	10	mW	
Pulse optical output power	P <sub>O(pulse)</sub>	12 *	mW	
LD reverse voltage	V <sub>R(LD)</sub>	2	V	
PD reverse voltage	V <sub>R(PD)</sub>	30	V	
Operating temperature	Topr	-10 to +50	O°	
Storage temperature	Tstg	-40 to +85	°C	

Note: Pulse condition : Pulse width  $\leq 1 \ \mu$ s, duty = 50%

## **Optical and Electrical Characteristics**

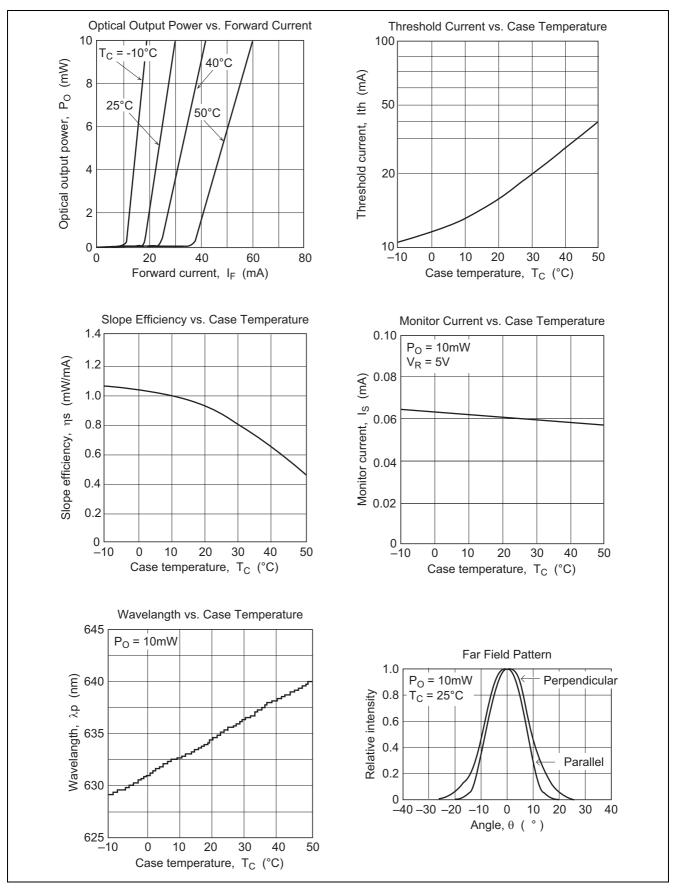
						$(T_{\rm C} = 25^{\circ}{\rm C})$
ltem	Symbol	Min	Тур	Max	Unit	Test Conditions
Threshold current	lth	—	20	35	mA	—
Slope efficiency	ηs	0.5	0.8	1.2	mW/mA	6 (mW) / (I <sub>(8mW)</sub> – I <sub>(2mW)</sub> )
Operating current	I <sub>OP</sub>	—	35	45	mA	$P_0 = 10 \text{ mW}$
Operating voltage	V <sub>OP</sub>	—	2.4	2.7	V	$P_0 = 10 \text{ mW}$
Lasing wavelength	λρ	630	635	640	nm	$P_0 = 10 \text{ mW}$
Beam divergence parallel to the junction	θ//	13	17	25	0	P <sub>O</sub> = 10 mW
Beam divergence perpendicular to the junction	θ⊥	13	20	25	0	P <sub>O</sub> = 10 mW
Aspect ratio	θ⊥/θ//	—	1.2	1.5	μm	$P_0 = 5 \text{ mW}, \text{ NA} = 0.55$
Monitor current	ls	0.03	0.06	0.12	mA	$P_0 = 10 \text{ mW}, V_{R(PD)} = 5 \text{ V}$

Notes: 1. The beam has 12 deg offset against the package reference plane. Please take account it mounted on aboard.

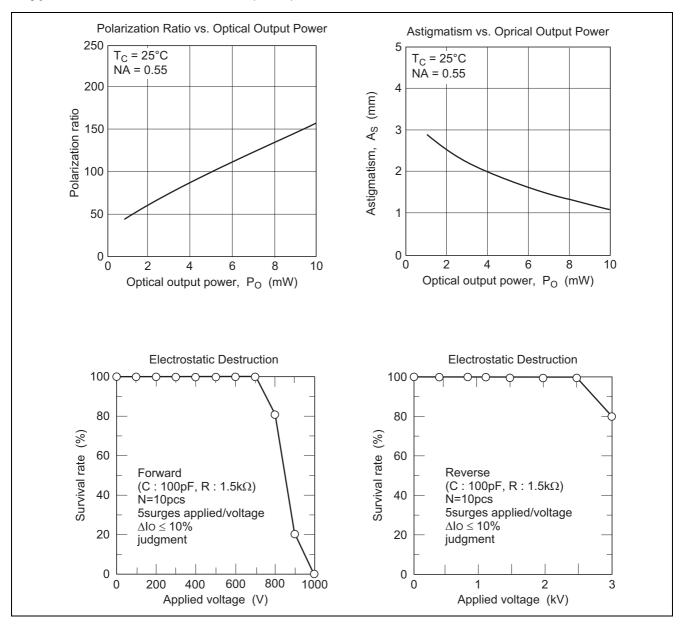
2. The beam divergence has dependence of temperature, if you use this device into your system please check on it enough before design.



## **Typical Characteristic Curves**



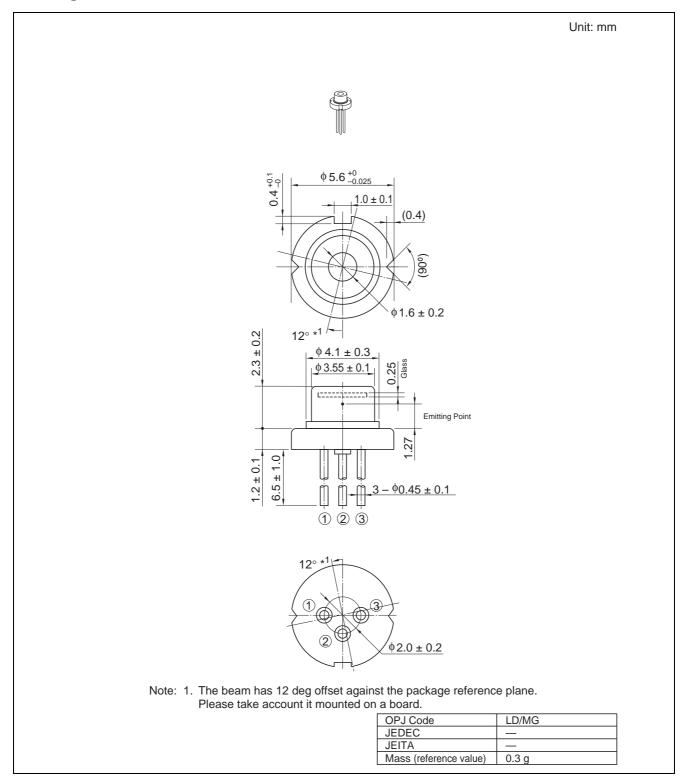




#### Typical Characteristic Curves (cont.)



### **Package Dimensions**





#### Cautions

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- 2. This product contains gallium arsenide (GaAs), which may seriously endanger your health even at very low doses. Please avoid treatment which may create GaAs powder or gas, such as disassembly or performing chemical experiments, when you handle the product.

When disposing of the product, please follow the laws of your country and separate it from other waste such as industrial waste and household garbage.

3. Definition of items shown in this CAS is in accordance with that shown in Opto Device Databook issued by OPJ unless otherwise specified.

## **Sales Offices**



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